

v02.0218

## HMC635LC4

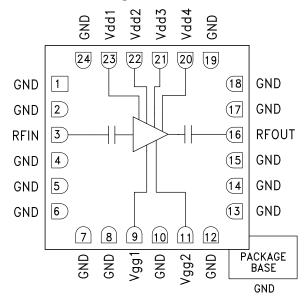
### GaAs PHEMT MMIC DRIVER AMPLIFIER, 18 - 40 GHz

#### **Typical Applications**

The HMC635LC4 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- LO Driver for Mixers
- Military & Space

#### **Functional Diagram**



#### Features

Gain: 18.5 dB <sup>[2]</sup> P1dB: +22 dBm <sup>[2]</sup> Output IP3: +27 dBm Saturated Power: +23.5 dBm @ 15% PAE <sup>[2]</sup> Supply Voltage: +5V @ 280 mA 50 Ohm Matched Input/Output 24 Lead Ceramic 4x4mm SMT Package: 16mm<sup>2</sup>

#### **General Description**

The HMC635LC4 is a GaAs PHEMT MMIC Driver Amplifier die which operates between 18 and 40 GHz. The amplifier provides 18.5 dB of gain, +27 dBm Output IP3, and +22 dBm of output power at 1 dB gain compression, while requiring 280 mA from a +5V supply. Ideal as a driver amplifier for microwave radio applications, or as an LO driver for mixers operating between 18 and 40 GHz, the HMC635LC4 is capable of providing up to +23.5 dBm of saturated output power at 15% PAE. The amplifier's I/Os are DC blocked and internally matched to 50 Ohms making it ideal for integration into Multi-Chip-Modules (MCMs).

#### **Electrical Specifications**

#### $T_{A} = +25^{\circ} C$ , Vdd= Vdd1, 2, 3, 4 = +5V, Idd= Idd1 + Idd2 + Idd3 + Idd4 = 280mA<sup>[1]</sup>

Min.	Тур.	Max.	Min.	Тур.	Max.	Units
18 - 36		36 - 40		GHz		
15	18.5		15	17.5		dB
	0.045	0.06		0.045	0.06	dB/ °C
	13			7		dB
	10			7		dB
19	22		16	21		dBm
	23.5			21.5		dBm
22	27		21	26		dBm
	7			7		dB
	280			280		mA
	15	18 - 36   15 18.5   0.045   13   10   19 22   23.5   22 27   7	18 - 36   15 18.5   0.045 0.06   13 10   19 22   23.5 22   27 7	18 - 36   15 18.5   15 18.5   13   10   19 22   23.5   22 27   21   7	18 - 36     36 - 40       15     18.5     15     17.5       0.045     0.06     0.045       13     7       10     7       19     22     16     21.5       22     27     21     26       7     9     7     7	18 - 36     36 - 40       15     18.5     15     17.5       0.045     0.06     0.045     0.06       13     7     10     7       19     22     16     21.5       22     27     21     26       7     7     7     10

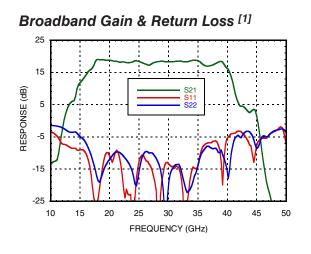
[1] Adjust Vgg1 = Vgg2 between -2 to 0V to achieve Idd= 280 mA Typical.

[2] Board loss subtracted out for gain, power and noise figure measurements.

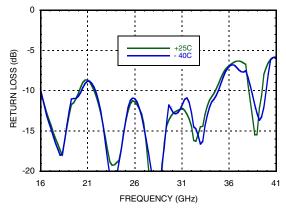
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



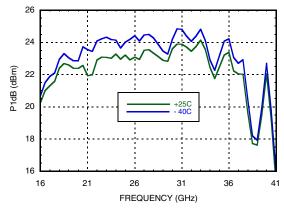
### GaAs PHEMT MMIC DRIVER AMPLIFIER, 18 - 40 GHz



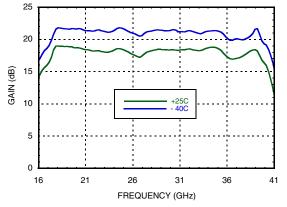
Input Return Loss vs. Temperature



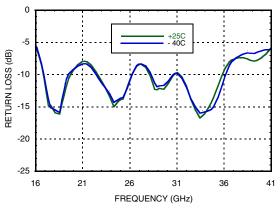




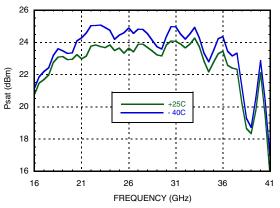








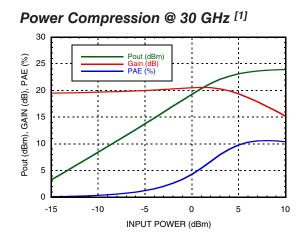
Psat vs. Temperature <sup>[1]</sup>



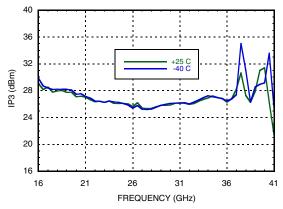
[1] Board loss subtracted out for gain, power and noise figure measurements.



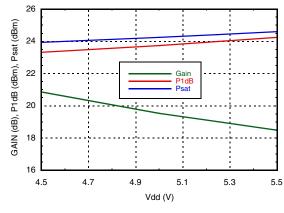
## GaAs PHEMT MMIC DRIVER AMPLIFIER, 18 - 40 GHz

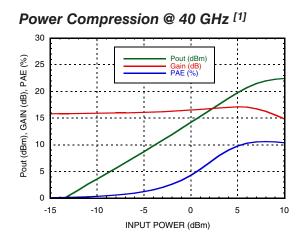


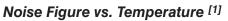
Output IP3 vs. Temperature

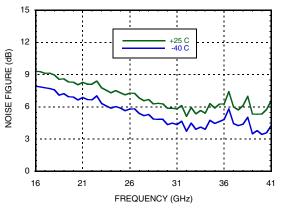


Gain & Power vs. Supply Voltage @ 30 GHz <sup>[1]</sup>

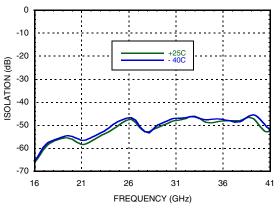








**Reverse Isolation vs. Temperature** 



[1] Board loss subtracted out for gain, power and noise figure measurements.



### GaAs PHEMT MMIC DRIVER AMPLIFIER, 18 - 40 GHz

#### Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, 2, 3, 4)	+5.5V	
Gate Bias Voltage (Vgg1, Vgg2)	-3 to 0V	
RF Input Power (RFIN)(Vdd = +5 Vdc)	15 dBm	
Channel Temperature	175 °C	
Continuous Pdiss (T= 70 °C) (derate 15.1 mW/°C above 70 °C)	1.575 W	
Thermal Resistance (channel to package base)	66.4 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	

#### Typical Supply Current vs. Vdd

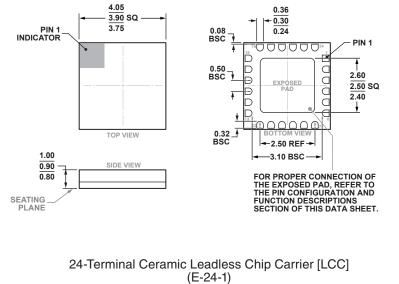
Vdd (V)	ldd (mA)
4.5	277
5.0	280
5.5	286

Note: Amplifier will operate over full voltage ranges shown above



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

#### **Outline Drawing**



Dimensions shown in millimeters.

#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC635LC4	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	H635 XXXX
[1] Max peak reflow temperature of 260 °C				
[2] 4-Digit lot number XXXX				

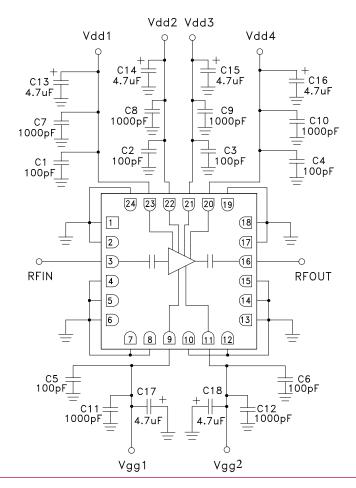


## GaAs PHEMT MMIC DRIVER AMPLIFIER, 18 - 40 GHz

#### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic	
1, 2, 4 - 8, 10, 12 - 15, 17 - 19, 24, Ground Paddle	GND	These pins and package bottom must be connected to RF/DC ground		
3	RFIN	This pad is AC coupled and matched to 50 Ohms.		
16	RFOUT	This pad is AC coupled and matched to 50 Ohms.		
9, 11	Vgg1, Vgg2	Gate control for amplifier, please follow "MMIC Amplifier Biasing Procedure" application note. See assembly diagram for required external components.	Vgg1 Vgg2	
20 - 23	Vdd4 - Vdd1	Power Supply Voltage for the amplifier. See assembly diagram for required external components.	OVdd4,3,2,1 	

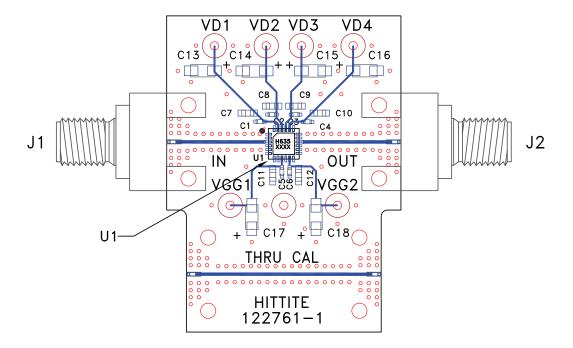
#### **Application Circuit**





### GaAs PHEMT MMIC DRIVER AMPLIFIER, 18 - 40 GHz

#### **Evaluation PCB**



#### List of Materials for Evaluation 122763 [1]

Item	Description
J1 - J2	2.92 mm PC Mount K-Connector
VD1 - VD4, VGG1, VGG2	DC Pin
C1 - C6	100 pF Capacitor, 0402 Pkg.
C7 - C12	1000 pF Capacitor, 0603 Pkg.
C13 - C18	4.7 µF Capacitor, Tantalum, Case A
U1	HMC635LC4 Driver Amplifier
PCB [2]	122761 Evaluation PCB <sup>[3]</sup>

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

[3] Due to the very high frequency operation of this product a custom LC4 PCB footprint and solder stencil are required for this design. Performance shown in this data sheet was produced using this custom footprint. DO NOT USE Hittite's standard LC4 footprint. Please contact Applications for details. The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices upon request.

## **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Analog Devices Inc.:

HMC635LC4 HMC635LC4TR 122763-HMC635LC4